Electronic Supplementary Material (ESI) for Journal of Materials Chemistry C.

Supporting Information

Enhanced ambipolar charge transport for efficient organic single crystal light-emitting transistors with narrowed ambipolar regime

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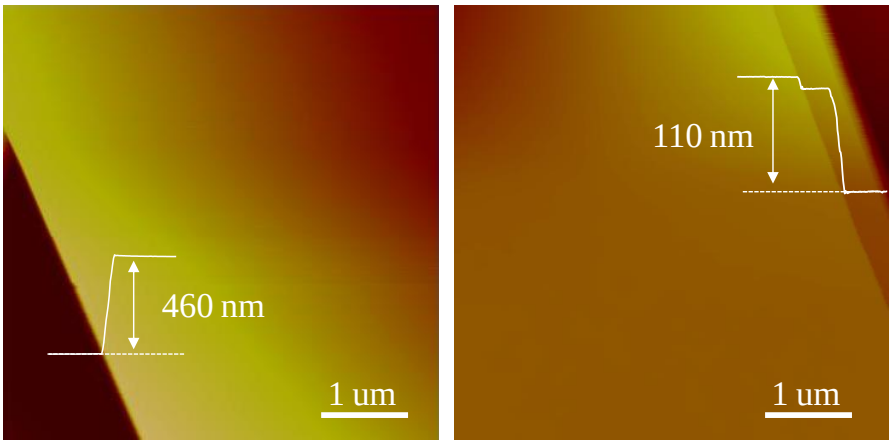

Fig S1 AFM image of typical DPA single crystals with two different thicknesses of 110 nm and 460 nm.

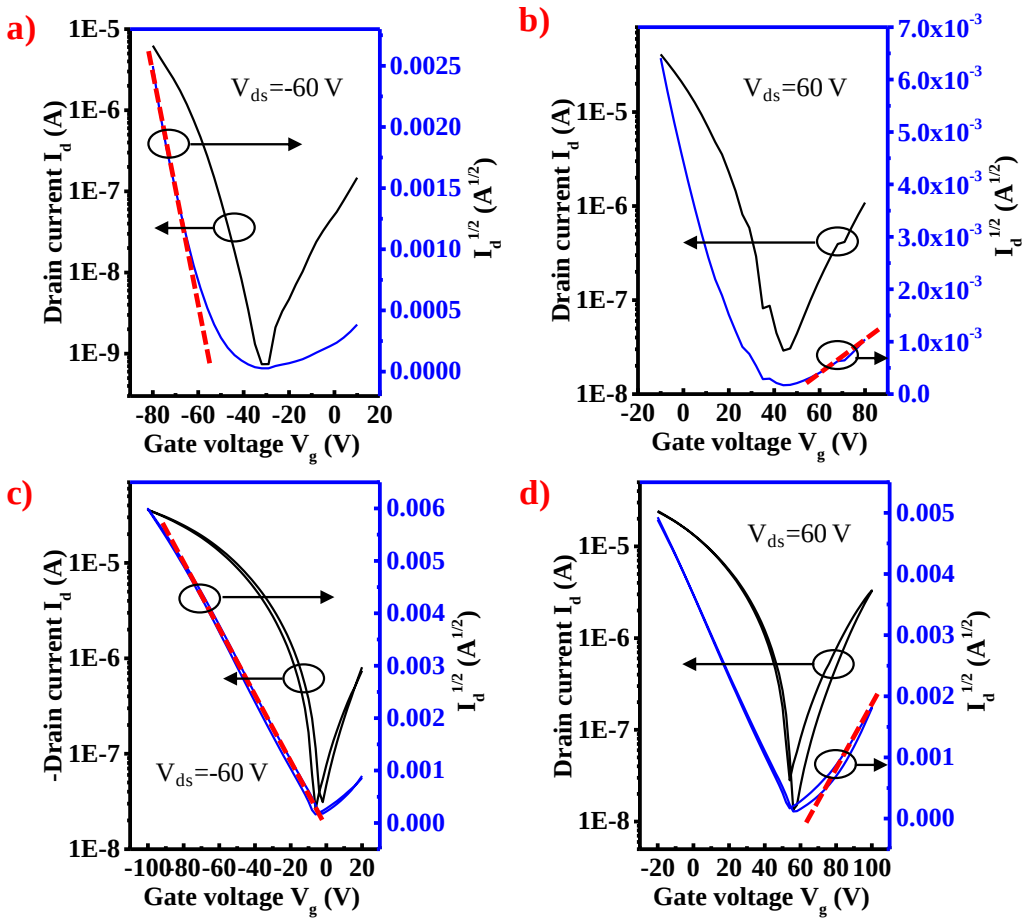

Fig S2 Typical p-channel (left) and n-channel (right) transfer curves of DPA single crystal OLETs with different electrodes and linear fit in red for threshold voltage and mobilities. (a, b) Au and Ca used as electrodes; (c, d) Au/MoO3 and Ca/CsF used as electrodes.

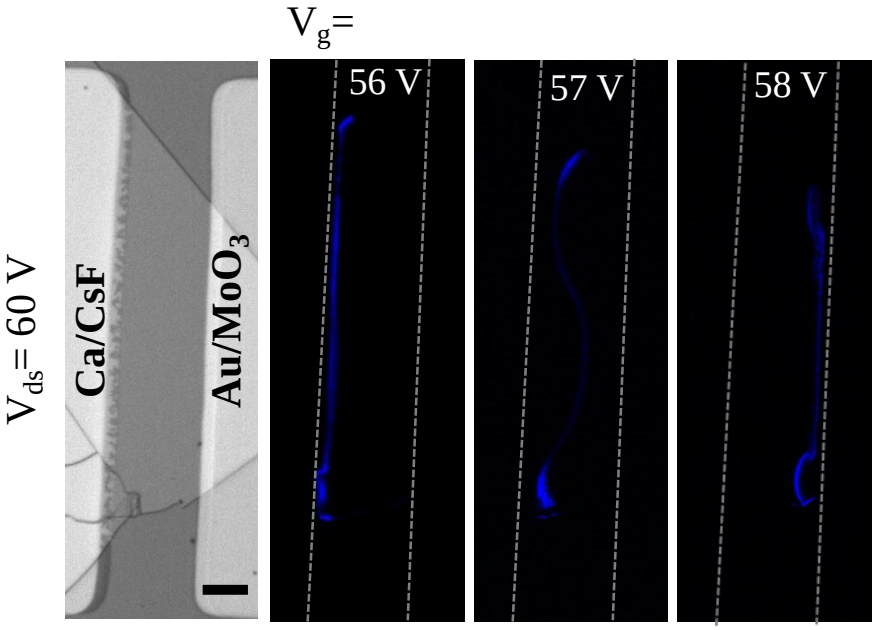

Figure S3 Optical images of light emission zone within n-operation channel for a DPA single crystal OLET with Au/MoO3 and Ca/CsF as electrodes. V_{ds} fixed at 60 V and V_g changed from 56 V to 58 V. The scale bar 50 μm.

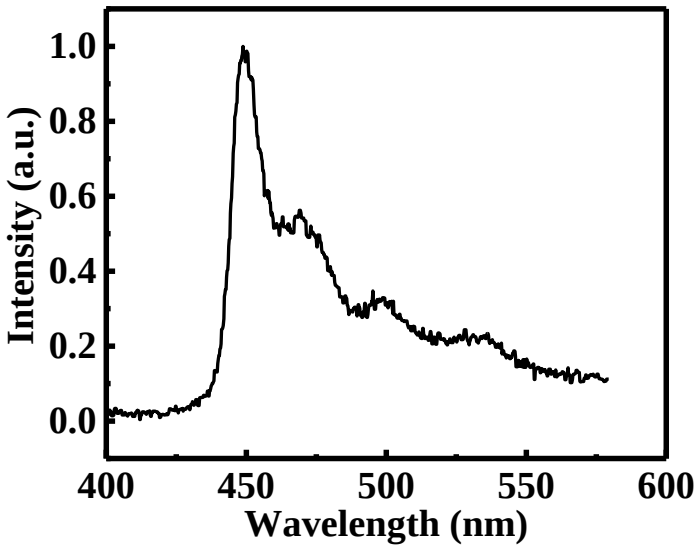

Fig S4 EL of a DPA single crystal OLET.